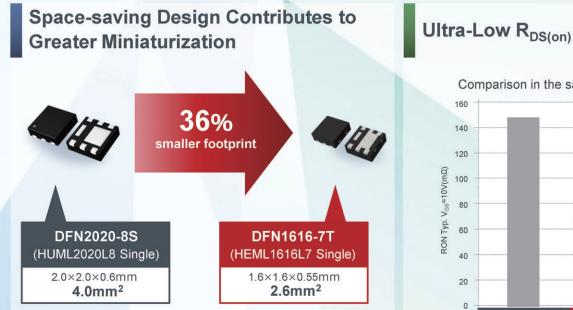
Featured Products

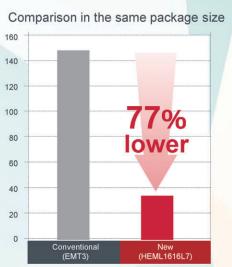




Compact high power package (DFN1616-7T) MOSFETs Optimized for Portable Devices

RW4xx series





Applications

- Smartphones
- · Portable devices (i.e. tablet computers, DSCs, GPS)
- Laptops



Supports a Variety of Circuit Types

Optimized for battery/load switches, LED backlighting, and more

32												
	Part No.	Polarity (ch)	P _D (W) T _a =25°C	V _{DSS} (V)	I _D (A)		$R_{DS(on)}$ N	lax(mΩ)		Qg Typ(nC)	Size (mm)	Package
						V _{GS} =10V	V _{GS} =4.5V	V _{GS} =2.5V	V _{GS} =1.8V	V _{GS} =4.5V		
Ne	7 RW4E075AJ				7.5	-	26	38		6.3		
	☆ RW4E065GN	Ν		30	6.5	22.5	31.6	Ι		2.0		
Ne	RW4E045AJ		1.5		4.5	_	40	58		4.0	1.6×1.6×0.55	
	☆ RW4E045AT	Ρ		-30	-4.5	48	70	-		5.3		
Ne	7 RW4C045BC			-20	-4.5	· 1	56	74	117	6.5		DFN1616-7T (HEML1616L7 Single)

Note) (): ROHM Package Type

DFN2020L8 Compact High Power (2W) Packages

Popular series compatible with a broad range of portable devices

Single Type	ingle Type Large current compatibility ideal for high-power switching applications											
Part No.	Polarity	P _D (W)	V _{DSS}	I _D (A)	A	/lax(mΩ)	Qg Typ(nC)	Size	Package			
	(ch)	T _a =25°C	(V)		V _{GS} =10V	V_{GS} =4.5V	V _{GS} =4.5V	(mm)				
RF4E110GN	N	2	30	11	11.3	16.5	3.5	2.0×2.0×0.6				
RF4E080GN	N	2	30	8	17.6	31.2	2.8	2.0^2.0^0.0	DFN2020-8S (HUML2020L8 Single)			

Note) (): ROHM Package Type

Dual Type

Broad drive voltage lineup offered in a space-saving 2-in-1 (dual) package

Part No.	Polarity	P _D (W)	V _{DSS} (V)	I _D (A)	$R_{DS(on)} Max(m\Omega)$					Qg Typ(nC)	Size	naskara	
Fait NO.	(ch)	T _a =25°C			V _{GS} =10V	V_{GS} =4.5V	V _{GS} =2.5V	V _{GS} =1.8V	V _{GS} =1.5V	V _{GS} =4.5V	(mm)	package	
UT6K3	N+N P+P		30	5.5	_	42	63	_	_	4.0			
UT6JA3			2	-20	-5.0	_	59	76	118	92 06	6.5	2.0×2.0×0.6	
UT6J3		2	-20	-3.0	_	85	95	155	260	8.5	2.0×2.0×0.0		
UT6JA2			-30	-4.0	70	103	_	_	Ι	3.4		DFN2020-8D (HUML2020L8 Dual)	

(unit:mm)

Note) (): ROHM Package Type

ROHM Co., Ltd.

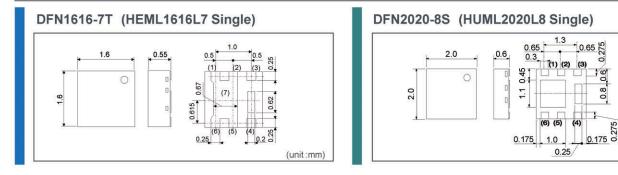
21 Saiin Mizosaki-cho, Ukyo-ku,

www.rohm.com

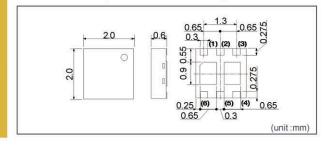
Kyoto 615-8585 Japan

Dimensions

SEMICONDUCTOR



DFN2020-8D (HUML2020L8 Dual)



The content specified in this document is correct as of July 1st, 2019.

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